# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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## BSP52T1G, BSP52T3G

## NPN Small-Signal Darlington Transistor

This NPN small signal Darlington transistor is designed for use in switching applications, such as print hammer, relay, solenoid and lamp drivers. The device is housed in the SOT-223 package, which is designed for medium power surface mount applications.

#### Features

- The SOT-223 Package can be soldered using wave or reflow. The formed leads absorb thermal stress during soldering, eliminating the possibility of damage to the die
- Available in 12 mm Tape and Reel Use BSP52T1 to Order the 7 Inch/1000 Unit Reel
- PNP Complement is BSP62T1
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CES</sub>	80	V
Collector-Base Voltage	V <sub>CBO</sub>	90	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Collector Current	Ι <sub>C</sub>	1.0	А
Total Power Dissipation (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	0.8 6.4	W mW/°C
Total Power Dissipation (Note 2) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.25 10	W mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to 150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance (Note 1) Junction-to-Ambient	$R_{\theta JA}$	156	°C/W
Thermal Resistance (Note 2) Junction-to-Ambient	$R_{\theta JA}$	100	°C/W
Maximum Temperature for Soldering Purposes Time in Solder Bath	ΤL	260 10	°C Sec

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

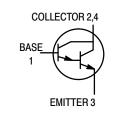
- Device mounted on a FR-4 glass epoxy printed circuit board using minimum recommended footprint.
- 2. Device mounted on a FR-4 glass epoxy printed circuit board using 1 cm<sup>2</sup> pad.

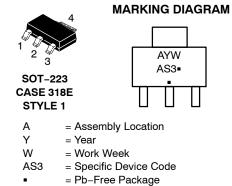


## **ON Semiconductor®**

http://onsemi.com

## MEDIUM POWER NPN SILICON SURFACE MOUNT DARLINGTON TRANSISTOR





(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BSP52T1G	SOT-223 (Pb-Free)	1000 / Tape & Reel
BSP52T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## BSP52T1G, BSP52T3G

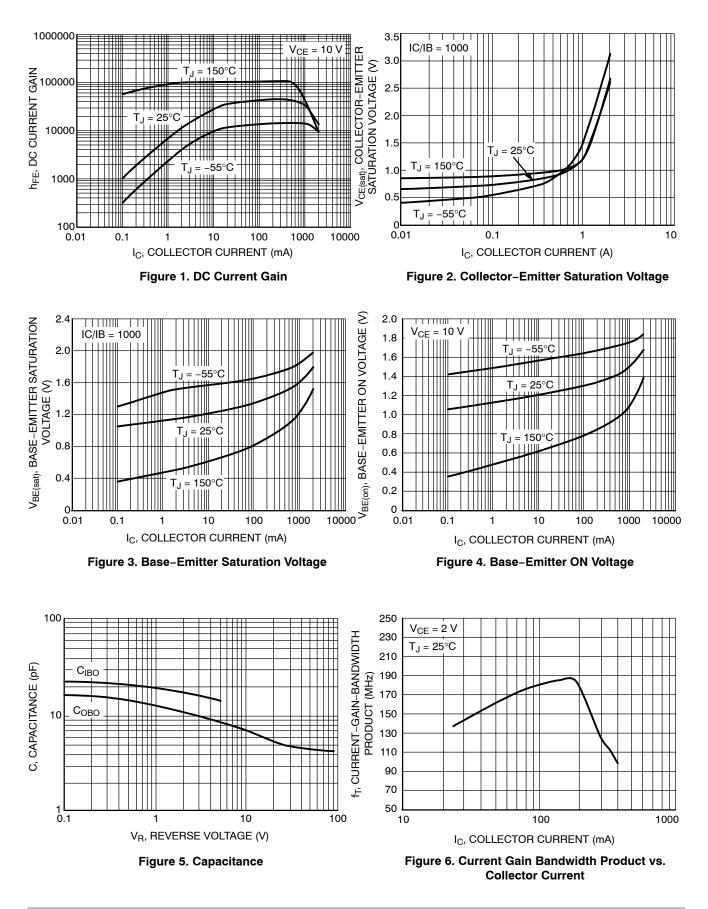
## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•	-	-	-	-
Collector-Base Breakdown Voltage $(I_C = 100 \ \mu\text{A}, I_E = 0)$	V <sub>(BR)CBO</sub>	90	_	-	V
Emitter-Base Breakdown Voltage ( $I_E = 10 \ \mu A, I_C = 0$ )	V <sub>(BR)EBO</sub>	5.0	_	_	V
Collector-Emitter Cutoff Current $(V_{CE} = 80 \text{ V}, V_{BE} = 0)$	ICES	_	_	10	μΑ
Emitter-Base Cutoff Current $(V_{EB} = 4.0 \text{ V}, I_C = 0)$	I <sub>EBO</sub>	_	_	10	μΑ
ON CHARACTERISTICS (Note 3)					
DC Current Gain (I <sub>C</sub> = 150 mA, V <sub>CE</sub> = 10 V) (I <sub>C</sub> = 500 mA, V <sub>CE</sub> = 10 V)	h <sub>FE</sub>	1000 2000	_		-
Collector-Emitter Saturation Voltage $(I_{C} = 500 \text{ mA}, I_{B} = 0.5 \text{ mA})$	V <sub>CE(sat)</sub>	_	_	1.3	V
Base-Emitter Saturation Voltage $(I_C = 500 \text{ mA}, I_B = 0.5 \text{ mA})$	V <sub>BE(sat)</sub>	-	-	1.9	V
SWITCHING CHARACTERISTICS					
Rise Time ( $V_{CC}$ = 10 V, $I_{C}$ = 150 mA, $I_{B1}$ = 0.15 mA)	t <sub>r</sub>	_	155	_	ns
Delay Time (V <sub>CC</sub> = 10 V, I <sub>C</sub> = 150 mA, I <sub>B1</sub> = 0.15 mA)	t <sub>d</sub>	_	205	-	ns
Storage Time (V <sub>CC</sub> = 10 V, I <sub>C</sub> = 150 mA, I <sub>B1</sub> = 0.15 mA, I <sub>B2</sub> = 0.15 mA)	t <sub>s</sub>	_	420	_	ns
Fall Time (V <sub>CC</sub> = 10 V, I <sub>C</sub> = 150 mA, I <sub>B1</sub> = 0.15 mA, I <sub>B2</sub> = 0.15 mA)	t <sub>f</sub>	_	365	_	ns

3. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

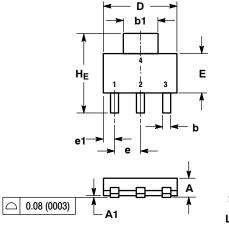
## BSP52T1G, BSP52T3G

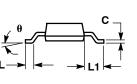




#### PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N



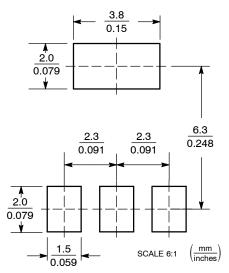


NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
c	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
Г	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

**SOLDERING FOOTPRINT\*** 



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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